

Publikačný seminár

J. Novák:

„Reinforcement role of GaP nanowires in a ZnO layer prepared by RF sputtering“

Vacuum

F. Gucmann:

„Optimisation of UV-assisted wet oxidation of GaAs“

Journal of Vacuum Science & Technology B

M. Ľapajna:

„Low-Temperature atomic layer deposition-grown Al₂O₃ gate dielectric for GaN/AlGaN/GaN MOS HEMTs: Impact of deposition conditions on interface state density“

Journal of Vacuum Science & Technology B

B. Zaťko:

„Radiation detector based on 4H-SiC used for thermal neutron detection“

Journal of Instrumentation

Čas: 13. január 2017 o 10:00 hod.

Miesto: veľká zasadačka EIÚ SAV, miestnosť 101